NSN 5961-00-113-7453

No Fiig: A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-113-7453 **Inclosure Material:** Glass **Overall Length:** 0.620 inches **Terminal Length:** 0.750 inches **Overall Diameter:** 0.075 inches **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 100.0 breakdown voltage, dc and 75.0 working peak reverse voltage **Current Rating Per Characteristic:** 75.00 milliamperes forward current, average absolute and 1.00 amperes forward current, average preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Special Features:** Shorting pin w/ integral diode **Precious Material And Location:** Terminal surfaces gold **Precious Material:** Gold **Test Data Document:** 89661-128c565 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 1 turret and 1 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**